Theoretical Investigations of the electronic, magnetic, and thermoelectric properties of Quaternary Heusler Alloys

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Bac •	kground/Relevance Thermoelectric (TE) materials are solid state devices that could be designed using two dissimilar materials such as n-type and p-type semiconductors. They are designed to convert thermal	 Approach Calculations using density functional the (DFT) were performed to investigate structural, dynamical, electronic, magnetic, a 	ory the and
	energy from a temperature gradient into electrical energy and visa versa.	thermoelectric properties of VTiRhZ (Z = Al, o In, Si, Ge, Sn) alloys.	Ga,
•	Quaternary Heusler alloys have received a great deal of attention due to their novel electronic structure, magnetic, and thermoelectric materials nature.	 The semi-classical Boltzmann transport theory is used to calculate the thermoelectric properties that include seebeck coefficient, 	
Innovation		electrical conductivity, and electronic thermal	
•	Using Quaternary Heusler Alloys in thermoelectric and spintronic applications.	conductivity of the materials.	
Key Results		Conclusions	
•	Electronic, magnetic and thermoelectric properties of VTiRhZ (Z = Al, Ga, In, Si, Ge, Sn) alloys are investigated.	 The band gap obtained using GGA-PBE approximation is slightly smaller than that obtained by GGA-mBJ. The calculations using GGA-mBJ functional are considered to give more reliable predictions for the band structure. 	
•	The total magnetic moment of VTiRhZ (Z=Al,Ga,In) was found to be 3µB, and for VTiRhZ (Z=Si, Ge, Sn) exhibit integer values of		
•	2µB. The value of the power factor per relaxation time ranges	• Quaternary Heusler Alloys can find significant applications as thermoelectric and spintronic materials.	
	between 7.2 × 10^{11} Wm ⁻¹ K ⁻² s ⁻¹ and 14×10^{11} Wm ⁻¹ K ⁻² s ⁻¹ .	Future Work	
	$\frac{1}{20} \frac{20}{100 \text{ K}} \frac{1}{100 \text{ K}} $	Calculating lattice thermal conductivity.	
		Calculating figure of merit.	